

## **Electronic processes in bismuth type doped semimetals**

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### **Abstract**

Properties of highly doped bismuth alloys with impurities of the VI group are investigated. Anomalous behaviour of statistical and kinetical characteristics dependence upon the impurity concentration is interpreted within the framework of a notion of impurity states in semimetal systems.

*Keywords: bismuth alloys, semimetal systems, semimetals*

### **References**

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